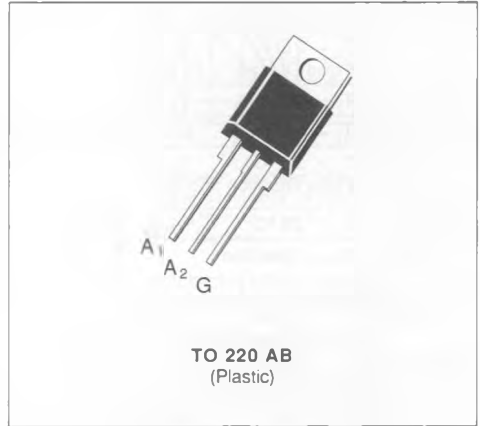


TRIACS

- GLASS PASSIVATED CHIP
- I_{GT} SPECIFIED IN FOUR QUADRANTS
- INSULATING VOLTAGE : 2500 V_{RMS}
- UL RECOGNIZED (E81734)

ADVANTAGES

- $I_H < 13$ mA
- HIGH SURGE CURRENT : $I_{TSM} = 100$ A


DESCRIPTION

Insulated triacs specified for light dimmer applications.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state Current (360° conduction angle)	$T_C = 85^\circ C$ 6	A
I_{TSM}	Non Repetitive Surge Peak on-state Current (T_j initial = 25 °C - Half sine wave)	$t = 8.3$ ms	105
		$t = 10$ ms	100
I^2t	I^2t Value for Fusing	$t = 10$ ms	50
di/dt	Critical Rate of Rise of on-state Current (1)	Repetitive $F = 50$ Hz	10
		Non Repetitive	50
T_{stg} T_j	Storage and Operating Junction Temperature Range	- 40 to 125 - 40 to 110	°C °C

Symbol	Parameter	BTA 06-			Unit
		200GP	400GP	600GP	
V_{DRM}	Repetitive Peak off-state Voltage (2)	200	400	600	V

(1) $I_G = 750$ mA $di/dt = 1$ A/ μ s

(2) $T_j = 110^\circ C$.

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to Ambient	60	°C/W
$R_{th(j-c)}$ DC	Junction to Case for DC	5.1	°C/W
$R_{th(j-c)}$ AC	Junction to Case for 360° Conduction Angle ($F = 50$ Hz)	3.8	°C/W

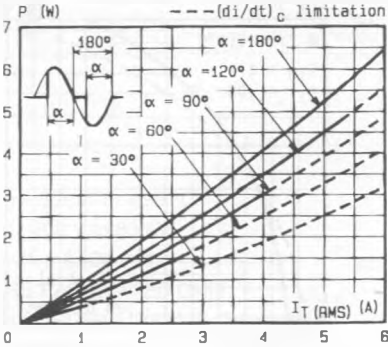


Fig. 1 - Maximum mean power dissipation versus RMS on-state current ($f = 60 \text{ Hz}$).

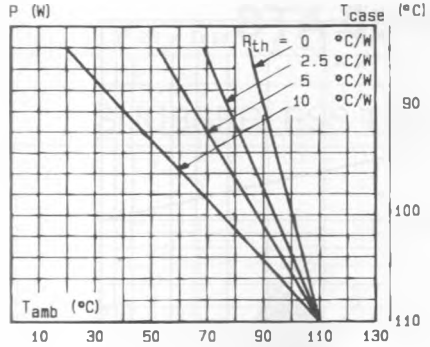


Fig. 2 - Correlation between maximum mean power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact.

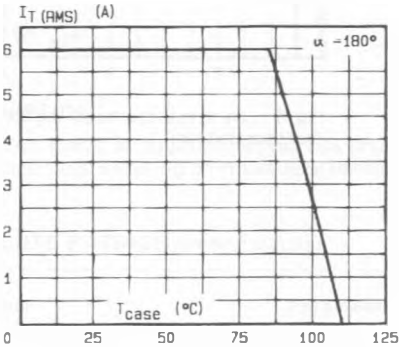


Fig. 3 - RMS on-state current versus case temperature.

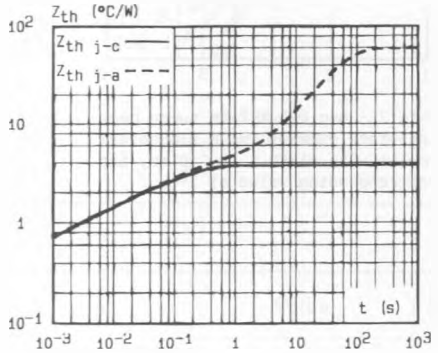


Fig. 4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

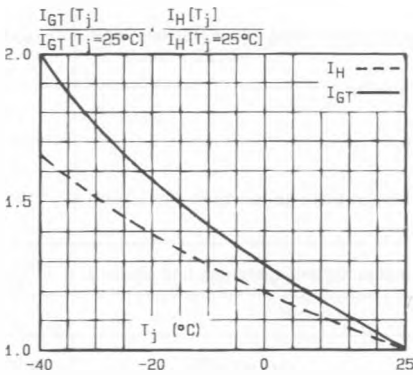


Fig. 5 - Relative variation of gate trigger current and holding current versus junction temperature.

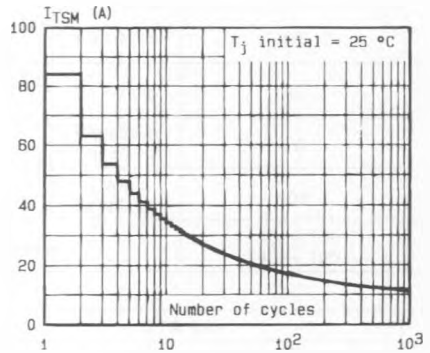


Fig. 6 - Non repetitive surge peak on-state current versus number of cycles.

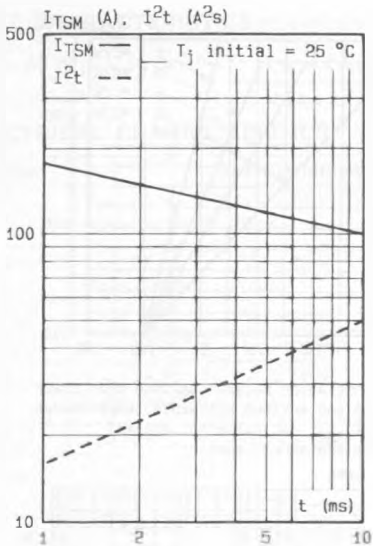


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10$ ms, and corresponding value of I^2t .

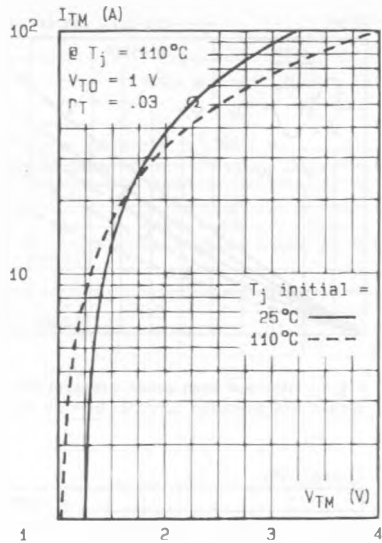


Fig.8 - On-state characteristics (maximum values)